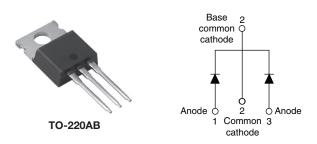
# www.vishay.com





PRODUCT SUMMARY					
I <sub>F(AV)</sub>	2 x 15 A				
V <sub>R</sub>	35 V, 40 V, 45 V				
V <sub>F</sub> at I <sub>F</sub>	0.56 V				
I <sub>RM</sub> max.	15 mA at 125 °C				
T <sub>J</sub> max.	175 °C				
E <sub>AS</sub>	27 mJ				
Package	TO-220AC				
Diode variation	Common cathode				

### FEATURES

- 175 °C T<sub>J</sub> operation
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- RoHS COMPLIANT HALOGEN FREE
- Guard ring for enhanced ruggedness and long term reliability
- AEC-Q101 qualified meets JESD 201 class 2 whisker test
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

The VS-30CTQ... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	L CHARACTERISTICS VALUES UNITS							
I <sub>F(AV)</sub>	Rectangular waveform	30	А					
V <sub>RRM</sub>	Range	35 to 45	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1060	А					
V <sub>F</sub>	20 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.56	V					
TJ	Range	-55 to 175	°C					

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-30CTQ035HN3 VS-30CTQ040HN3 VS-30CTQ045HN3								
Maximum DC reverse voltage	V <sub>R</sub>	35	40	45	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>		40	45	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS			
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 127 °C,	30					
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	1060	А			
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	256				
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \ ^\circ C, \ I_{AS} = 3.0 \ A, \ L = 4.40 \ r$	20	mJ				
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero Frequency limited by T <sub>J</sub> maximur		3.0	А			

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ELECTRICAL SPECIFICATIONS
---------------------------

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS			
		15 A	T <sub>1</sub> = 25 °C	0.62			
Maximum forward voltage drop See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	30 A	1j=25 C	0.76	V		
	¥FM <sup>(1)</sup>	15 A	T _ 105 °C	0.56			
		30 A	T <sub>J</sub> = 125 °C	0.70			
Maximum reverse leakage curent	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	2	mA		
See fig. 2	IRM ("	T <sub>J</sub> = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	15			
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ , (test signal rar	900	pF			
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 m	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs		

#### Note

Γ

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2  $\,\%$ 

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to 175	°C		
Maximum thermal resistance,	R <sub>thJC</sub>	DC operation See fig. 4	3.25			
junction to case per leg	<b>h</b> thJC	DC operation	1.63	°C/W		
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50			
Approximate weight			2.0	g		
Approximate weight			0.07	oz.		
minimu	m		6 (5)	kgf ⋅ cm		
Mounting torque maximu	ım		12 (10)	(lbf ⋅ in)		
			30CT0	Q035H		
Marking device		Case style TO-220AB	30CT0	Q040H		
			30CT0	Q045H		



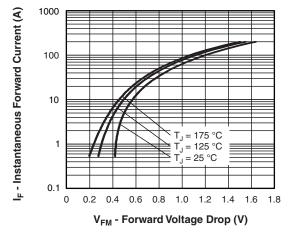


Fig. 1 - Maximum Forward Voltage Drop Characteristics

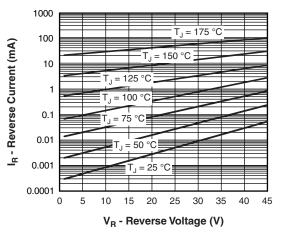


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

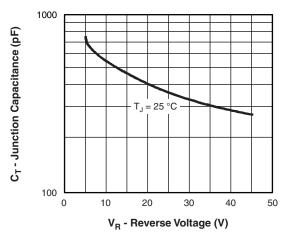


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

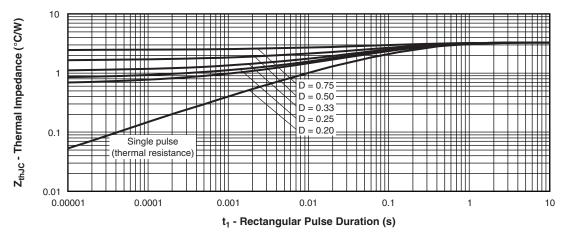


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

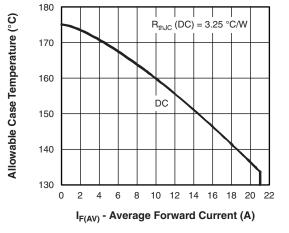
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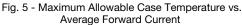
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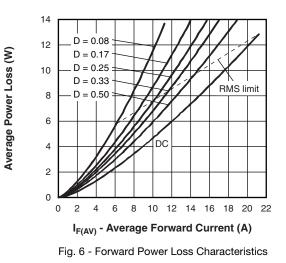


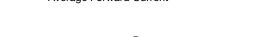
### VS-30CTQ0..HN3 Series

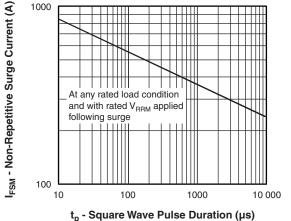
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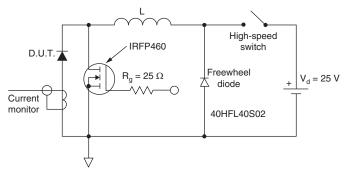


Fig. 8 - Unclamped Inductive Test Circuit

# VS-30CTQ0..HN3 Series



### **ORDERING INFORMATION TABLE**

Device code	VS-	30	С	т	Q	045	н	N3
				<u> </u>				
		2	3	4	5	6	$\overline{7}$	8
	_							
	1	- Visl	nay Sen	niconduo	ctors pro	oduct		
	2 -	Cur	ent rati	ng (30 =	30 A)			
	3 -	Circ	Circuit configuration:					
		C =	Commo	on catho	de			
	4 -	Pac	kage:					
		Т =	TO-220	)				
	5 -	Sch	ottky "Q	" series			035 = 3	35 V
	6 -	- Volt	age rati	nas —			040 = 4	
	7		0	101 qua	lified		045 = 4	45 V
				•	meu			
	8 -			ntal digit				
		• N	3 = Hal	ogen-fre	e, RoHS	S comp	liant, an	d totally

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-30CTQ035HN3	50	1000	Antistatic plastic tube					
VS-30CTQ040HN3	50	1000	Antistatic plastic tube					
VS-30CTQ045HN3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95222							
Part marking information	TO-220AB-N3	www.vishay.com/doc?95028					





**TO-220AB** 

#### **DIMENSIONS** in millimeters and inches





.ead	assignments

**Diodes** 

1. - Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIN	IETERS	INC	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- <sup>(2)</sup> Lead dimension and finish uncontrolled in L1
- <sup>(3)</sup> Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left( 4\right) }$  Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 10.51 0.414 10.11 0.398 3,6 Е E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 L L1 3.32 3.82 0.131 0.150 2 ØΡ 3.54 3.73 0.139 0.147 2.60 0.102 Q 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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